



# BC857AT, BT, CT

45V PNP SMALL SIGNAL TRANSISTOR IN SOT523

## Features

- BV<sub>CEO</sub> > -45V
- I<sub>C</sub> = -100mA Collector Current
- Epitaxial Planar Die Construction
- Ultra-Small Surface Mount Package
- Complementary NPN Type: BC847AT, BT, CT
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

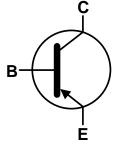
## **Mechanical Data**

- Case: SOT523
- Case Material: Molded Plastic. "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads.
  Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.002 grams (Approximate)

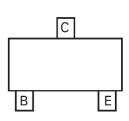


SOT523

Top View



Device Symbol



Pin-Out Top View

## Ordering Information (Note 4)

Product	Compliance	Marking	Reel Size (inches)	Tape Width (mm)	Quantity per Reel
BC857AT-7-F	AEC-Q101	3V	7	8	3,000
BC857BT-7-F	AEC-Q101	3W	7	8	3,000
BC857CT-7-F	AEC-Q101	3G	7	8	3,000

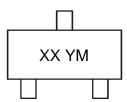
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



 $\begin{array}{l} XX = \mbox{Product Type Marking Code} \\ YM = \mbox{Date Code Marking} \\ Y \mbox{ or } \overline{Y} = \mbox{Year (ex: F = 2018)} \\ M \mbox{ or } \overline{M} = \mbox{Month (ex: 9 = September)} \end{array}$ 

Date Code Key	y
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Notes:

Year	2018	2	019	2020	2021	2022	2023	2024	4 20	25	2026	2027	2028
Code	F		G	Н		J	K	L	Ν	Л	Ν	0	Р
Mont	h	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	;	1	2	3	4	5	6	7	8	9	0	Ν	D



## Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CBO</sub>	-50	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	V
Emitter-Base Voltage	V <sub>EBO</sub>	-6	V
Collector Current	Ιc	-100	mA

### Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

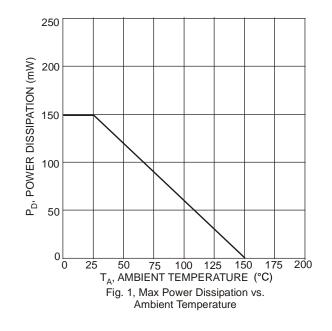
Characteristic	Symbol	Value	Unit
Power Dissipation (Note 5)	PD	150	mW
Thermal Resistance, Junction to Ambient (Note 5)	R <sub>0JA</sub>	833	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

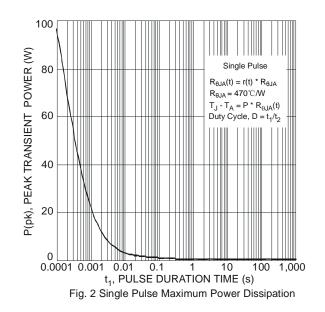
### ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge – Human Body Model	ESD HBM	4,000	V	ЗA
Electrostatic Discharge – Machine Model	ESD MM	400	V	С

Notes: 5. For a device mounted with the collector lead on minimum recommended pad layout 1oz copper that is on a single-sided 1.6mm FR-4 PCB; device is measured under still air conditions whilst operating in a steady-state. 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

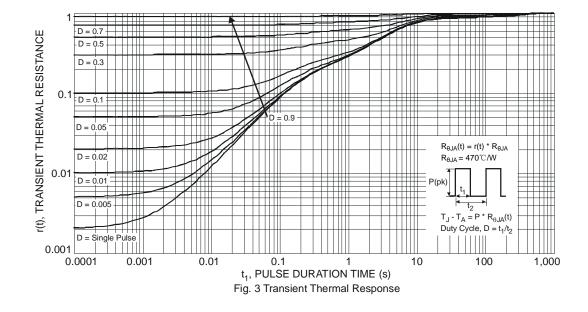
# Thermal Characteristics and Derating Information







# Thermal Characteristics and Derating Information (Cont.)



Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Collector-Base Breakdown Voltage		BV <sub>CBO</sub>	-50			V	$I_{\rm C} = -100 \mu A, I_{\rm E} = 0$
Collector-Emitter Breakdown Voltage		BV <sub>CEO</sub>	-45			V	$I_{C} = -1mA, I_{B} = 0$
Emitter-Base Breakdown Voltage		BV <sub>EBO</sub>	-6	—	_	V	$I_E = -100 \mu A$ , $I_C = 0$
ON CHARACTERISTICS (Note 7)				-			
DC Current Gain A B C		hfe	125 220 420	 290 520	250 475 800	  _	$V_{CE} = -5V, I_C = -2mA$
Collector-Emitter Saturation Voltage	V <sub>CE</sub> (SAT)		_	-300 -650	mV	$I_{C} = -10mA, I_{B} = -0.5mA$ $I_{C} = -100mA, I_{B} = -5mA$	
Base-Emitter Saturation Voltage	V <sub>BE(SAT)</sub>	_	-700 -900		mV	$I_{C} = -10mA, I_{B} = -0.5mA$ $I_{C} = -100mA, I_{B} = -5mA$	
Base-Emitter Voltage	V <sub>BE(ON)</sub>	-600	_	-750 -820	mV	$V_{CE} = -5V, I_C = -2mA$ $V_{CE} = -5V, I_C = -10mA$	
Collector-Emitter Cutoff Current	I <sub>СВО</sub>	_	_	-15 -4	nA µA	V <sub>CB</sub> = -30V V <sub>CB</sub> = -30V, T <sub>A</sub> = +150°C	
SMALL SIGNAL CHARACTERISTIC	S						
Output Capacitance	COBO	_	—	4.5	pF	V <sub>CB</sub> = -10V, f = 1MHz	
Current Gain-Bandwidth Product		f <sub>T</sub>	100	—	_	MHz	$V_{CE} = -5V, I_C = -10mA, f = 100MHz$
Noise Figure		NF	_		10	dB	$I_{C} = -0.2mA, V_{CE} = -5V,$ $R_{S} = 2k\Omega, f = 1MHz,$ BW = 200Hz

7. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%. Note:



# Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

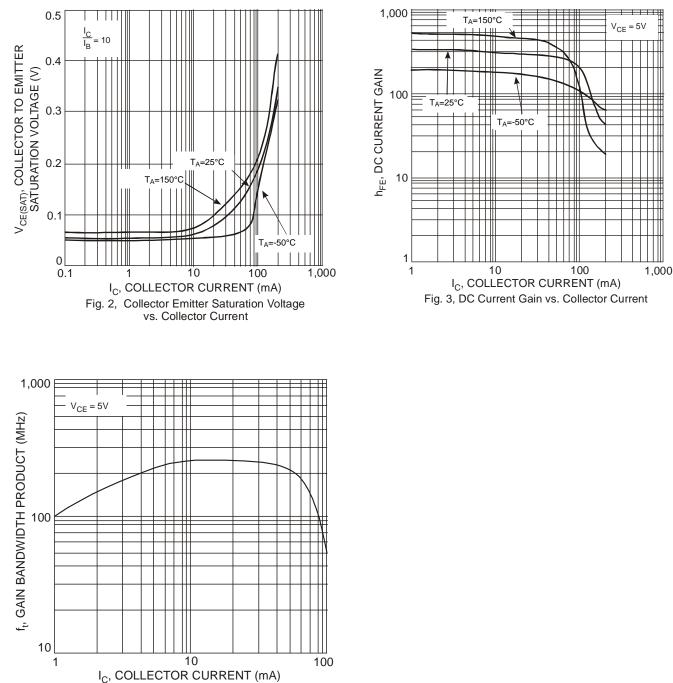
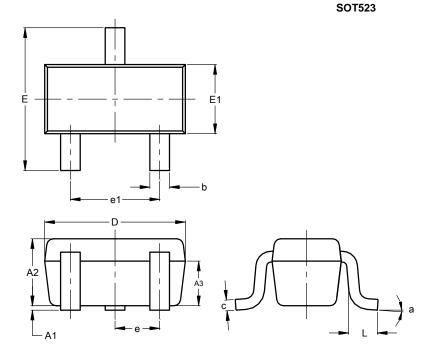


Fig. 4, Gain Bandwidth Product vs. Collector Current



# Package Outline Dimensions

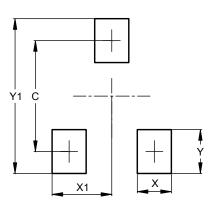
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT523								
Dim	Min	Max	Тур						
Α	0.60	0.80	0.75						
A1	0.00	0.10	0.05						
A3	0.45	0.65	0.50						
b	0.15	0.30	0.22						
С	0.10	0.20	0.12						
D	1.50	1.70	1.60						
E	1.45	1.75	1.60						
E1	0.75	0.85	0.80						
е		0.50 BS	С						
e1	0.90	1.10	1.00						
L	0.20	0.40	0.33						
а	0°		8°						
A	All Dimensions in mm								

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT523

Dimensions	Value		
С	1.29		
Х	0.40		
X1	0.70		
Y	0.51		
Y1	1.80		



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